

HL8325G GaAlAs Laser Diode

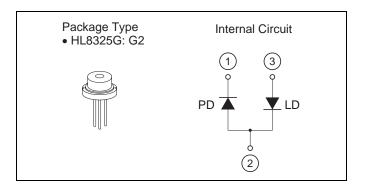
ODE2051-00 (M) Rev.0 Aug. 01, 2008

Description

The HL8325G is a high-power 0.8 μ m band GaAlAs laser diode with a TQW (triple quantum well) structure. Its internal circuit configuration is suitable for operation on a single positive supply voltage. It is suitable as a light source for optical disk memories, card readers and various other types of optical equipment.

Features

- Infrared light output: $\lambda p = 820$ to 840 nm
- High power: standard continuous operation at 40 mW (CW), pulsed operation at 50 mW
- Built-in monitor photodiode
- Single longitudinal mode



Absolute Maximum Ratings

			$(T_{\rm C} = 25^{\circ}{\rm C})$
ltem	Symbol	Ratings	Unit
Optical output power	Po	40	mW
Pulse optical output power	P _{O(pulse)}	50 *	mW
Laser diode reverse voltage	V _{R(LD)}	2	V
Photo diode reverse voltage	V _{R(PD)}	30	V
Operating temperature	Topr	-10 to +60	°C
Storage temperature	Tstg	-40 to +85	°C

Note: Pulse condition : Pulse width = 1 μ s, duty = 50%

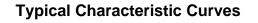
Optical and Electrical Characteristics

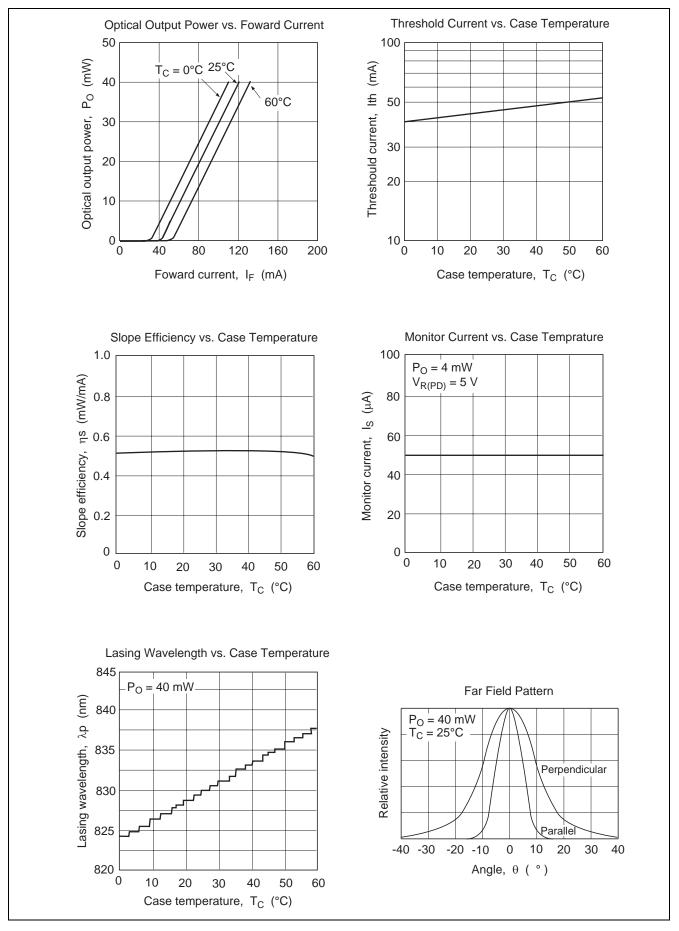
 $(T_{C} = 25^{\circ}C)$

2500

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	lth	—	40	70	mA	—
Slope efficiency	ηs	0.4	0.5	0.9	mW/mA	24 (mW) / (I _(32mW) – I _(8mW))
Beam divergence parallel to the junction	θ//	7	10	14	0	$P_0 = 40 \text{ mW}, \text{FWHM}$
Beam divergence perpendicular to the junction	θ⊥	18	22	32	o	$P_0 = 40 \text{ mW}, \text{FWHM}$
Astigmatism	As	—	5	—	μm	$P_0 = 4 \text{ mW}, \text{ NA} = 0.4$
Lasing wavelength	λρ	820	830	840	nm	$P_0 = 40 \text{ mW}$
Monitor current	Is	20	40	130	μΑ	$P_O = 4 \text{ mW}, V_{R(PD)} = 5 \text{ V}$

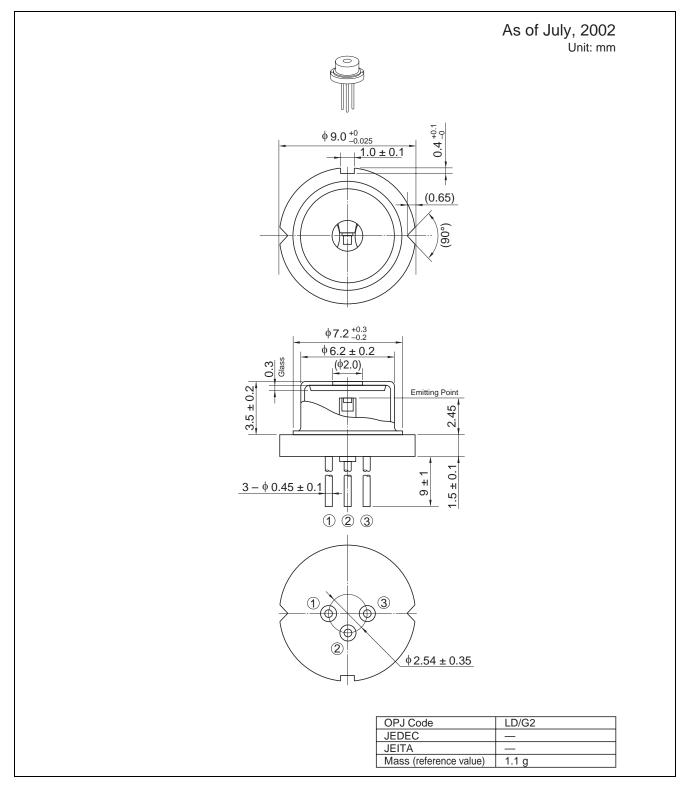






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Package Dimensions





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- 7. Contact our sales office for any questions regarding this document or OPJ products.
- 1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.

When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.

3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

Sales Offices



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